LA6542M

## 4-Channel Bridge (BTL) Driver for CD-ROM

## Overview

The LA 6542 M is a 4 -channel bridge (BTL) driver developed for CD-ROM applications.

## Functions

- 4-channel power amplifier with bridge circuit (BTL)
- $\mathrm{I}_{\mathrm{O}} \max : 1 \mathrm{~A}$
- Integrated muting circuit
(MUTE: Output OFF at Low, output ON at High. MUTE1 is for channels 1 and 2, and MUTE2 for channels 3 and 4.)
- Slew rate $0.5 \mathrm{~V} / \mu \mathrm{s}$
- Integrated thermal shutdown circuit


## Package Dimensions

unit: mm
3204-MFP36SLF


## Specifications

Maximum Ratings at $\mathbf{T a}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Conditions | Ratings | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Maximum supply voltage 1 | $\mathrm{V}_{\mathrm{CC}} \mathrm{max}$ |  | 14 | V |
| Maximum supply voltage 2 | $V_{S} \max$ | $\mathrm{V}_{\mathrm{S}} 1,2$ | 14 | V |
| Maximum input voltage | $\mathrm{V}_{\text {IN }}$ max | Input pins $\mathrm{V}_{\text {IN }} 1$ to 4 | 13 | V |
| Mute pin voltage | $\mathrm{V}_{\text {MUTE }} \mathrm{max}$ |  | 13 | V |
| Allowable power dissipation | Pd max | IC only | 0.9 | W |
| Operating temperature | Topr |  | -20 to +75 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | Tstg |  | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

Operating Conditions at $\mathrm{Ta}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Conditions | Ratings | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Recommended operation voltage 1 | $\mathrm{V}_{\mathrm{CC}}$ |  | 4 to 13 | V |
| Recommended operation voltage 2-1 | $\mathrm{V}_{\mathrm{S}}$ |  | 4 to 13 | V |
| Recommended operation voltage 2-2 | $\mathrm{V}_{\mathrm{S}}{ }^{2}$ |  | 4 to 13 | V |

${ }^{*} \mathrm{~V}_{\mathrm{CC}} \geq \mathrm{V}_{\mathrm{S}} 1,2$

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Electrical Characteristics at $\mathrm{V}_{\mathrm{CC}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=5 \mathrm{~V}, \mathbf{T a}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Conditions | Ratings |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | min | typ | max |  |
| $\mathrm{V}_{\text {CC }}$ no-load current drain | $\mathrm{ICC}^{1}$ | All outputs ON (MUTE1, MUTE2: High) | 5 | 10 | 20 | mA |
|  | $\mathrm{I}_{\mathrm{CC}}{ }^{2}$ | All outputs OFF (MUTE1, MUTE2: Low) |  | 5 | 10 | mA |
| $\mathrm{V}_{S} 1$ no-load current drain | $\mathrm{I}^{1-1}$ | CH1, 2 ON (MUTE1, MUTE2: High) |  | 10 | 30 | mA |
|  | $\mathrm{I}_{\text {S }} 1-2$ | CH1, 2 OFF (MUTE1, MUTE2: Low) |  |  | 4 | mA |
| $\mathrm{V}_{\mathrm{S}} 2$ no-load current drain | $\mathrm{I}^{2} 2-1$ | CH3, 4 ON (MUTE1, MUTE2: High) |  | 10 | 30 | mA |
|  | Is 2 -2 | CH3, 4 OFF (MUTE1, MUTE2: Low) |  |  | 4 | mA |
| Output offset voltage | $\mathrm{V}_{\text {OF }} 1$ to 4 | Potential difference between plus and minus outputs for CH 1 to CH 4 | -50 |  | 50 | mV |
| Input voltage range | $\mathrm{V}_{\text {IN }}$ | Input voltage range for $\mathrm{V}_{\text {IN }} 1$ to $\mathrm{V}_{\text {IN }} 4$ | 0.5 |  | 5 | V |
| Output voltage (source) | Vsource | Plus and minus outputs at high level | 4.4 | 4.7 |  | V |
|  |  | $\mathrm{I}_{\mathrm{O}}=700 \mathrm{~mA}$ |  |  |  |  |
| (sink) | Vsink | Plus and minus outputs at low level |  | 0.3 | 0.6 | V |
|  |  | $\mathrm{I}_{0}=700 \mathrm{~mA}$ |  |  |  |  |
| Closed circuit voltage gain | VG | Voltage gain between BTL amplifiers |  | 6 |  | dB |
| Slew rate | SR | (Note 1) |  | 0.5 |  | $\mathrm{V} / \mu \mathrm{s}$ |
| Mute ON voltage | $\mathrm{V}_{\text {MUTE }}$ | MUTE1, MUTE2 voltage when output is ON (Note 2) |  | 1.5 | 2 | V |
| Mute ON current | $I_{\text {mute }}$ | MUTE1, MUTE2 current when output is ON (Note 2) |  | 6 | 10 | $\mu \mathrm{A}$ |

Note 1: Guaranteed design value
Note 2: MUTE works on all channels. At High, amplifier output is ON and at Low amplifier output is OFF (output impedance becomes HI).


## Pin Assignment



Top view

Pin Function

| Pin number | Pin name | Equivalent circuit | Pin function |
| :---: | :---: | :---: | :---: |
| $\begin{gathered} \hline 1,2 \\ 17,18 \\ 19,20 \\ 35,36 \end{gathered}$ | RF |  | Substrate (minimum potential) |
| $\begin{gathered} \hline 7,9 \\ 11,13 \end{gathered}$ | $\begin{aligned} & \hline \mathrm{V}_{\mathrm{IN}} 1, \mathrm{~V}_{\mathrm{IN}}{ }^{2} \\ & \mathrm{~V}_{\mathrm{IN}} 3, \mathrm{~V}_{\mathrm{IN}} 4 \end{aligned}$ |  | Input pins for CH 1 and CH 2 Input pins for CH 3 and CH 4 |
| $\begin{gathered} \hline 8,10 \\ 12,14 \end{gathered}$ | $\begin{aligned} & \text { VG1, VG2 } \\ & \text { VG3, VG4 } \end{aligned}$ |  | Input pins for CH 1 and CH 2 (for gain adjustment) Input pins for CH3 and CH4 (for gain adjustment) |
| 16 | $\mathrm{V}_{\mathrm{CC}}$ | $28$ | Power supply |
| 22 | $\mathrm{V}_{\text {REF }} \mathrm{OUT}$ |  | Level shift circuit reference voltage ( $\mathrm{V}_{\text {REF }} 1$ buffer amplifier output*) |
| 3 | $\mathrm{V}_{\text {OUT }}$ |  | OP amp output |
| 4 | $\mathrm{V}_{\text {IN }}{ }^{-}$ |  | OP amp inverted input |
| 5 | $\mathrm{V}_{1 \mathrm{~N}^{+}}$ |  | OP amp non-inverted input |
| $\begin{gathered} 6 \\ 15 \end{gathered}$ | MUTE1 <br> MUTE2 |  | CH1, CH2 output ON/OFF CH3, CH4 output ON/OFF |
| 21 | $\mathrm{V}_{\text {REF }} \mathrm{IN}$ |  | Level shift circuit reference voltage input ( $\mathrm{V}_{\text {REF }}$ buffer amplifier input ${ }^{*}$ ) |
| 23 24 26 27 28 29 31 32 | $\begin{aligned} & \hline \mathrm{V}_{0} 8 \\ & \mathrm{~V}_{0} 7 \\ & \mathrm{~V}_{0} 6 \\ & \mathrm{~V}_{0} 5 \\ & \mathrm{v}_{0} 4 \\ & \mathrm{~V}_{0} 3 \\ & \mathrm{~V}_{0} 2 \\ & \mathrm{~V}_{0} 1 \end{aligned}$ |  | CH 4 inverted output (AMP8 output) CH4 non-inverted output (AMP7 output) CH3 inverted output (AMP6 output) CH3 non-inverted output (AMP5 output) CH2 inverted output (AMP4 output) CH2 non-inverted output (AMP3 output) CH1 inverted output (AMP2 output) CH1 non-inverted output (AMP1 output) |
| 25 | $\mathrm{V}_{\mathrm{S}}{ }^{2}$ |  | CH3 (AMP5, AMP6), CH4 (AMP7, AMP8) output stage power supply |
| 30 | $\mathrm{V}_{\mathrm{S}} 1$ |  | CH1 (AMP1, AMP2), CH2 (AMP3, AMP4) output stage power supply |
| 33 | $\mathrm{V}_{\text {SS }}$-OUT |  | Output stage reference voltage ( $\mathrm{V}_{\mathrm{SS}} 1 / 2$ : typ) ( $\mathrm{V}_{\mathrm{REF}}$ 2 buffer amplifier output ${ }^{*}$ ) |
| 34 | $\mathrm{V}_{\text {SS }}$ |  | Connect to VS1, VS2 (resistance split) to generate $\mathrm{V}_{\mathrm{SS}} \mathrm{OUT}$ |

*See block diagram on next page.

## Block Diagram



A11139
System Diagram (relationship between power supply and MUTE)


## Sample Application Circuit



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## Gain Setting (input pins and adjustment pins)

A simplified diagram of $\mathrm{V}_{\mathrm{IN}}$ and $V G$ is shown below.

1) Consider an $11 \mathrm{k} \Omega$ (typ.) resistor inserted between $V_{I N}$ and $V G$.
2) When not the pin $V G$ but the pin $V_{I N}$ is used alone, the $B T L$ gain (between $V_{O^{+}}$and $V_{O^{-}}$) is set to 6 dB ( 0 dB for $A M P$ only). This also applies for the case when $\mathrm{V}_{\mathrm{IN}}$ is not used and an $11 \mathrm{k} \Omega$ external resistor is connected to VG for input.
3) Gain is set by the input impedance as seen from point $A$.

When VG only is used and the external resistor is $R$, the BTL gain (between $V_{O^{+}}$and $V_{O^{-}}$) is $20 \log (11 \mathrm{k} \Omega / \mathrm{R})+6 \mathrm{~dB}$.
When an $11 \mathrm{k} \Omega$ resistor is inserted between $\mathrm{V}_{I N}$ and $V G$, and input is via $\mathrm{V}_{\mathrm{IN}}$, the combined resistance $R z$ as seen from point $A$ is $R z=5.5 \mathrm{k} \Omega$. Gain is
$20 \log (11 \mathrm{k} \Omega / 5.5 \mathrm{k} \Omega)+6 \mathrm{~dB}=12 \mathrm{~dB}$.


## Offset Voltage

This IC incorporates a level shifter circuit. The input references the $\mathrm{V}_{\mathrm{REF}}$ to be applied, and references the voltage $\left(\mathrm{V}_{\mathrm{SS}}-\mathrm{V}_{\mathrm{BE}}\right.$ (0.7))/2V to be output.
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